



# Mid Infra-red Devices Opportunities and Challenges

Professor Jon Heffernan University of Sheffield

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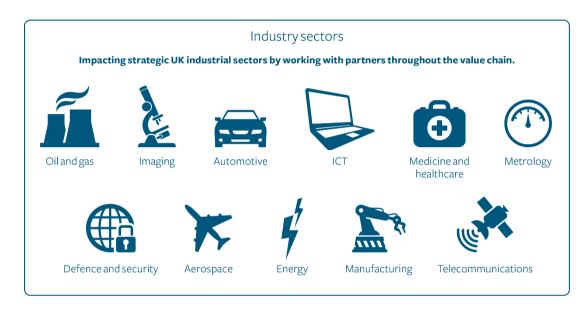


#### *<b>EFUTURE PHOTONICSHub*

Introduction Advancing manufacturing of next-generation light technologies



- Photonics is an underpinning ٠ discipline
- Huge value across a broad range of ٠ industry sectors
- Challenge is the integration of many ٠ technologies into low-cost, high value manufacturing processes
- In this session we focus on Mid ٠ Infra-red Photonics as a strongly emerging opportunity and a key capability within the HUB



#### Grand Challenge: Integration

Developing new low-cost, efficient manufacturing processes to integrate technology platforms and to enable new devices and components including lasers, sensors, new light sources, modulators, transceivers and photonics subsystems etc.





#### **FUTURE PHOTONICS**Hub Advancing manufacturing of next-generation light technologies Today's Presentations



### **MIR Devices (Professor Jon Heffernan, Sheffield)**

Introduction to laser, LED, detector capabilities in Sheffield

## Silicon Photonics Platforms (Professor Goran Mashanovich, Southampton)

- Introduction to the Silicon and Germanium based integrated Photonics platforms in Southampton

### Chalcogenide Photonics (Professor Dan Hewak, Southampton)

- Introduction to MIR fibre and optoelectronic technologies at Southampton

### **Optical Coherence Tomography (Professor Steve Matcher, Sheffield)**

- Introduction to OCT technologies and illustration of integration needs and opportunities

## MIR European Foundry (Iwan Davies, IQE Europe)

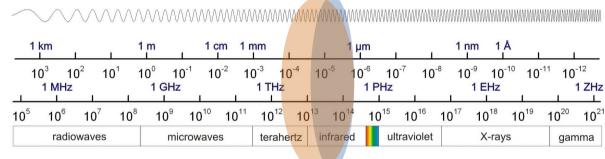
- Introduction to a new European foundry and scale-up opportunities out of Hub work

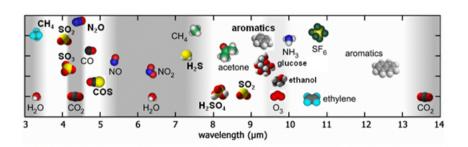


#### **EFUTURE PHOTONICS**Hub Advancing manufacturing of next-generation light technologies Why Mid Infra Red?



# Much of the value in MIR Photonics is in accessing optical activity of environmental substances and materials and low loss transmission in free space





#### Detection limits using diode laser spectroscopy

Molecule	<b>ppb</b> mid-IR (λ)	ppb Near-IR (λ)
H2O	2.0 5.94 μm	60 1.39 µm
CO2	0.13 4.23 µm	3000 1.96 µm
CO	0.75 4.6 µm	500 2.33 μm
NO	5.8 5.25 μm	60000 1.8 µm
CH4	1.7 3.26 μm	600 1.65 μm
HCl	0.83 3.4 µm	150 1.79 µm
H2OC	8.4 3.55 μm	50000 1.93 µm
NH3	0.8 10.3 μm	800 1.5 μm

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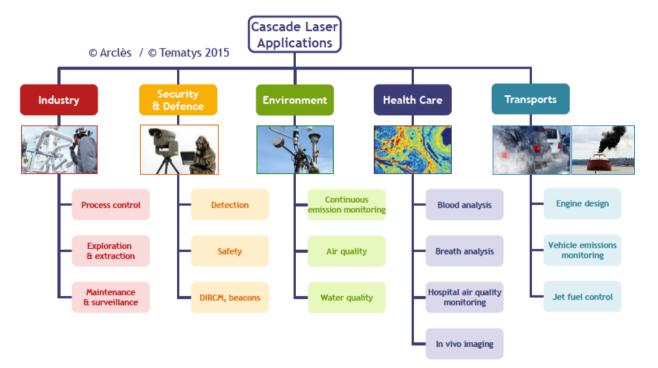
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Diverse application space with technological, societal and regulatory drivers for innovation

Applications



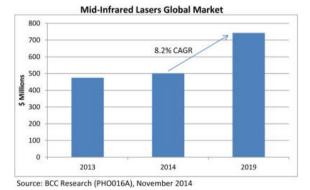


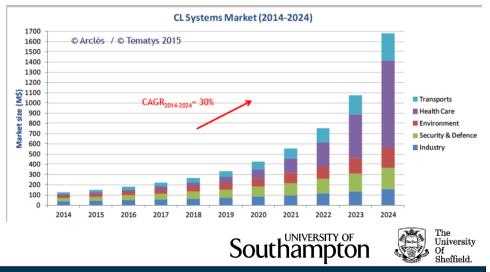
#### **<u>EFUTURE PHOTONICS</u>Hub** Advancing manufacturing of next-generation light technologies Market Opportunities



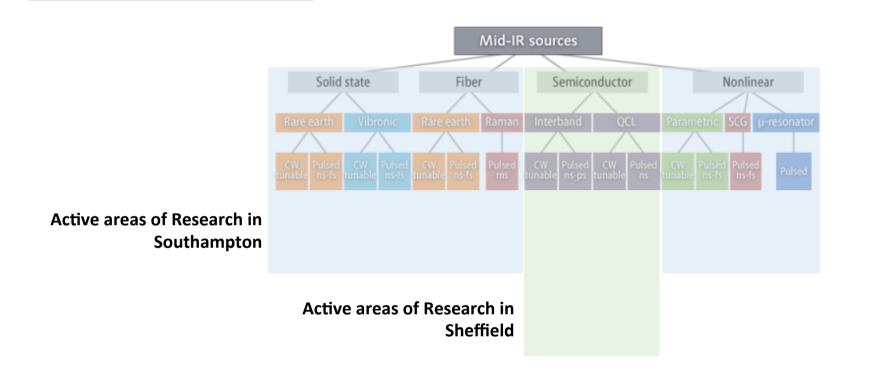
Significant growth in Mid-IR laser markets as new technology innovations have emerged and manufacturability of technology such as QCLs has become established. CAGR 8%

 Larger applications markets in sensing, monitoring, countermeasures and healthcare, CAGR 30%





**EFUTURE PHOTONICSHub** Advancing manufacturing of next-generation light technologies EPSRC Engineering and Physical Sciences Research Council



MIR Devices

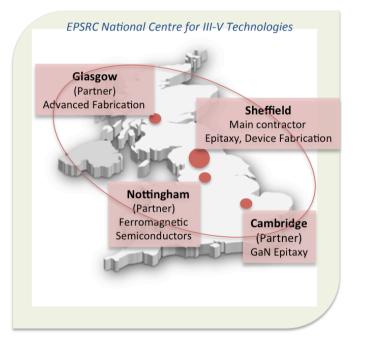


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# III-V Semiconductor Capabilities in the Hub



### Longstanding experience in the growth of III-V semiconductors in University of Sheffield Material supply to the Hub through the EPSRC National Centre for III-V Technologies (since 1979)





Extensive Epitaxy and device processing capability including:

- 9 MBE and MOVPE reactors
- High spec device fabrication cleanrooms
- Full suite of materials and device characterization
- Working with many companies as well as academia

- ISO9001 certified







All major III-V materials and devices supplied covering spectral range from UV to THz

# **Epitaxy**

- Arsenides (MBE and MOVPE)
- Phosphides (MBE and MOVPE)
- Antimonides (MBE)
- Dilute Nitrides (MBE)
- Nitrides (MOVPE, MBE)
- Novel materials (Bismides, ferromagnetics...)
- Quantum Dots and Nanowires
- 2D materials and Van der Waals epitaxy (MBE)

# DEVICES

- Edge Emitting Lasers
- VCSELs
- VECSELs, SESAMs
- Quantum Cascade Lasers
- LEDs, SLEDs
- Multijunction Solar Cells
- Detectors (including SPADs)
- Modulators

## • Single Photon emitters

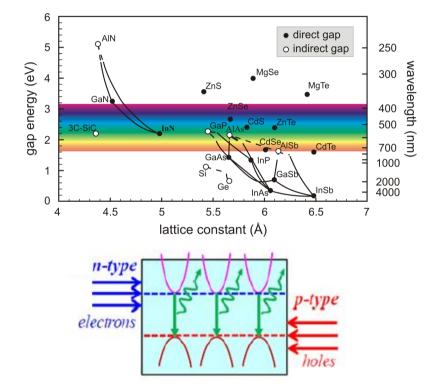
- Photonic crystal devices
- Microcavities
- RTDs
- FETs, HEMTs and power electronics
- Nanostructures
- Magnetic heterostructures





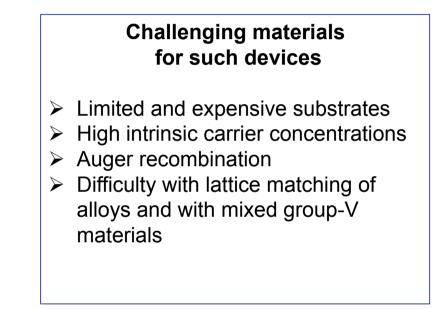
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**MIR Devices** 

Conventional interband emitters such as lasers and LEDs (and detectors in reverse)



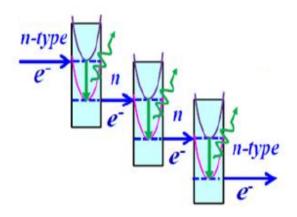
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# Solution: Cascade Structures

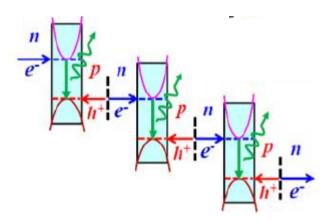




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Intersubband Cascade structures



Type II Interband Cascade structures



# **Quantum Cascade Lasers**

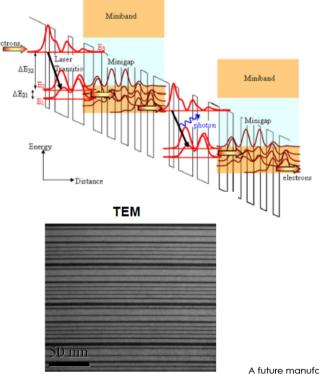


- + Emission determined by quantum confined energy levels in Quantum wells => Not dependent on bandgaps (not exactly true)
- + Emission from ~3micron to THz region (with appropriate design)

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- + Broad gain profile allowing for large tuning range and very narrow linewidths in single devices
- Very challenging epitaxy (thousands of layers)
- Short and long wavelength regimes are still difficult with low temperature operation





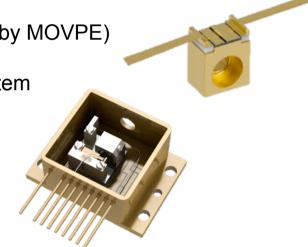
# Sheffield a pioneer in Quantum Cascade Lasers



- $\succ$  QCLs by MBE and MOVPE (first group in world to demonstrate by MOVPE)
- GaAs/AIGaAs system, InGaAs/InP system, InGaAs/InGaSb system
- Wavelengths from 3.1 micron to 12 micron  $\geq$
- Watt-class outputs  $\geq$
- DFB structures for single mode narrow linewidth  $\geq$
- Our lasers have been incorporated in a variety of systems including into commercial systems for gas  $\geq$ and environmental sensing A future manufacturing research hub



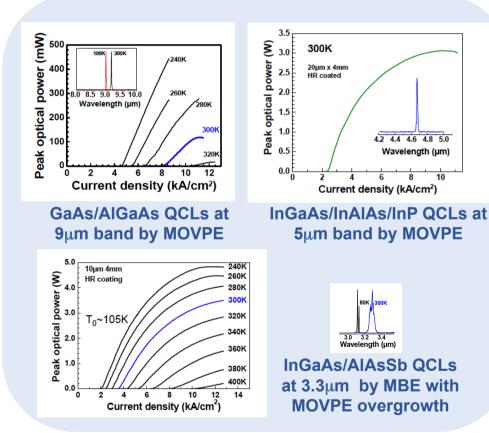






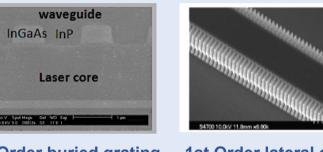
## **Quantum Cascade Lasers**





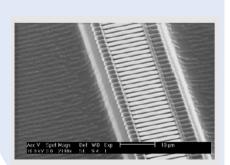
**<sup>₽</sup>FUTURE PHOTONICS**Hub

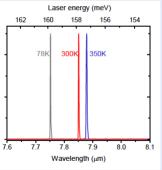
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3<sup>rd</sup> Order buried grating

#### **1st Order lateral grating**





**DFB laser Operation** 



# **New Directions and Manufacturability**



## Remaining key challenges and opportunities at device level include:

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- Mass manufacture of QCLs is still to be achieved. Partially market limited but very challenging epitaxy
- Further progress in wall-plug efficiency, high power, low threshold, tunable and mode-locked lasers still required
- > More work on thermal management and packaging technologies required



#### **EFUTURE PHOTONICS**Hub Advancing manufacturing of next-generation light technologies New Directions within the HUB



# Hub will address major new device innovation and significant advances in applications-driven integration for manufacturing

- > We will be developing improved QCLs
- We will be developing Interband Cascade lasers for improved device performance and manufacturability
- We will develop Sb-based MOVPE for manufacturing of short wavelength QCL and ICLs
- LEDs and detectors also based on these approaches are possible



# Other III-V Technologies available within the HUB

## Detectors

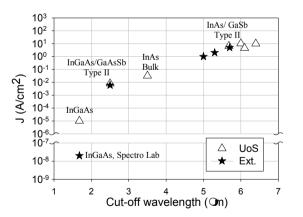
 Critical component in high sensitivity applications. MIR is particularly challenging

High quality Epitaxy

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- Broad materials coverage for full wavelength range
- Detector design and innovation

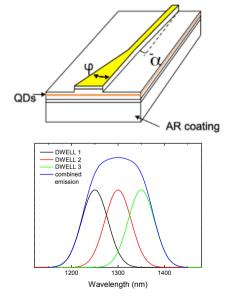


# SLEDs

Broad spectral emission

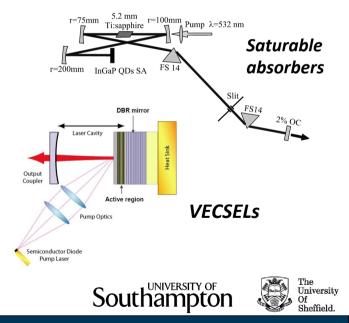
**Beyond Sources** 

- Less critical epitaxy than lasers
- Limited power applications



## Solid-state Hybrids

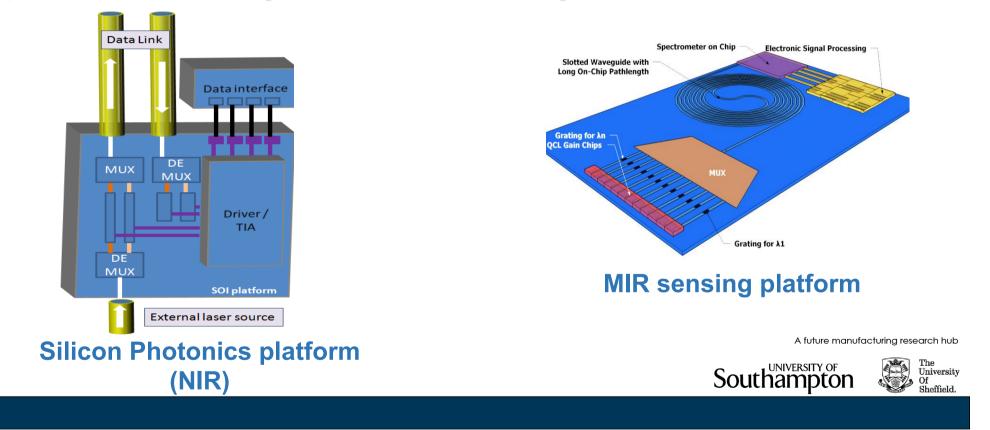
- Semiconductor component in solid-state laser systems
- Variety of challenges at MIR



#### **<u>EFUTURE PHOTONICSHub</u>** Advancing manufacturing of next-generation light technologies MIR-Sensing Platform



Hub will address major new device innovation and significant advances in applications-driven integration for manufacturing







World class III-V Semiconductor Epitaxy and device fabrication facilities available through the Hub:

- Innovation in semiconductor devices in the Mid-infra red
- > Developing integrated applications-led platforms
- Working with industry and academic partners to develop high value manufacturing processes



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# Thank you for your attention

